INTEGRATED CIRCUITS

DATA SHEET

74LVC04AHex inverter

Product specification Supersedes data of 2002 Mar 08 2003 Feb 24





Hex inverter 74LVC04A

FEATURES

- 5 V tolerant inputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 to 3.6 V
- CMOS low power consumption
- · Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- Complies with JEDEC standard no. 8-1A
- ESD protection: HBM EIA/JESD22-A114-A exceeds 2000 V MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 to +85 °C and -40 to +125 °C.

DESCRIPTION

The 74LVC04A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3 or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 and 5 V environment.

The 74LVC04A provides six inverting buffers.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25 \, ^{\circ}C$; $t_r = t_f \le 2.5 \, \text{ns}$.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	propagation delay nA to nY	$C_L = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$	2.1	ns
C _I	input capacitance		4.0	pF
C _{PD}	power dissipation capacitance per gate	V _{CC} = 3.3 V; notes 1 and 2	15	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = GND$ to V_{CC} .

ORDERING INFORMATION

TYPE NUMBER	PACKAGE										
I THE NUMBER	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE						
74LVC04AD	−40 to +125 °C	14	SO14	plastic	SOT108-1						
74LVC04ADB	–40 to +125 °C	14	SSOP14	plastic	SOT337-1						
74LVC04APW	−40 to +125 °C	14	TSSOP14	plastic	SOT402-1						
74LVC04ABQ	−40 to +125 °C	14	DHVQFN14	plastic	SOT762-1						

Hex inverter 74LVC04A

FUNCTION TABLE

See note 1.

INPUT	ОИТРИТ
nA	nY
L	Н
Н	L

Note

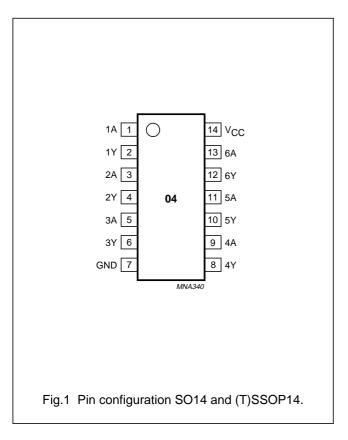
1. H = HIGH voltage level;

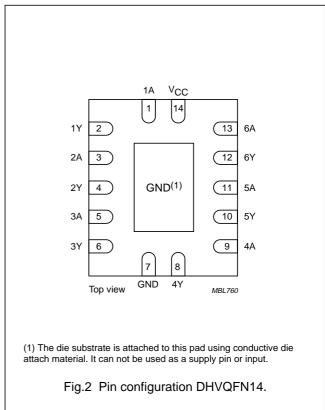
L = LOW voltage level.

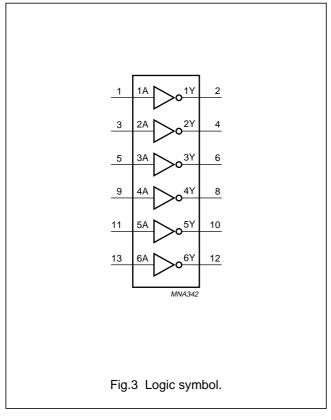
PINNING

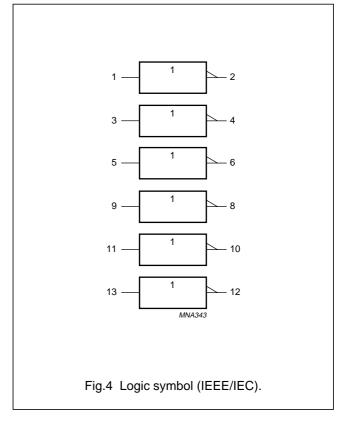
PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1Y	data output
3	2A	data input
4	2Y	data output
5	3A	data input
6	3Y	data output
7	GND	ground (0 V)
8	4Y	data output
9	4A	data input
10	5Y	data output
11	5A	data input
12	6Y	data output
13	6A	data input
14	V _{CC}	supply voltage

Hex inverter 74LVC04A

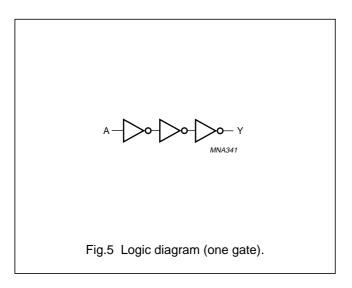








Hex inverter 74LVC04A



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage	for maximum speed performance	2.7	3.6	V
		for low-voltage applications	1.2	3.6	V
VI	input voltage		0	5.5	V
Vo	output voltage		0	V _{CC}	V
T _{amb}	operating ambient temperature		-40	+125	°C
t _r , t _f	input rise and fall times	V _{CC} = 1.2 to 2.7 V	0	20	ns/V
		V _{CC} = 2.7 to 3.6 V	0	10	ns/V

LIMITING VALUES

In accordance with the absolute maximum rating system (IEC 60134); voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	supply voltage		-0.5	+6.5	V
I _{IK}	input diode current	V ₁ < 0	_	-50	mA
VI	input voltage	note 1	-0.5	+6.5	V
I _{OK}	output diode current	$V_O > V_{CC}$ or $V_O < 0$	_	±50	mA
Vo	output voltage	note 1	-0.5	V _{CC} + 0.5	V
Io	output source or sink current	$V_O = 0$ to V_{CC}	_	±50	mA
I_{CC} , I_{GND}	V _{CC} or GND current		_	±100	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	power dissipation per package	$T_{amb} = -40 \text{ to } +125 \text{ °C}; \text{ note } 2$	_	500	mW

Notes

- 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 2. For SO14 packages: above 70 °C derate linearly with 8 mW/K.

For SSOP14 and TSSOP14 packages: above 60 $^{\circ}$ C derate linearly with 5.5 mW/K.

For DHVQFN14 packages: above 60 $^{\circ}\text{C}$ derate linearly with 4.5 mW/K.

Hex inverter 74LVC04A

DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

0)/440.01	DAD AMETED	TEST CONE	DITIONS		T)(D(1)		
SYMBOL	PARAMETER	OTHER	V _{CC} (V)	MIN.	TYP. ⁽¹⁾	MAX.	UNIT
T _{amb} = -40	to +85 °C					•	
V _{IH}	HIGH-level input voltage		1.2	V _{CC}	_	-	V
			2.7 to 3.6	2.0	_	_	V
V _{IL}	LOW-level input voltage		1.2	_	_	GND	V
			2.7 to 3.6	_	_	0.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		$I_{O} = -100 \mu\text{A}$	2.7 to 3.6	V _{CC} – 0.2	_	_	V
		$I_{O} = -12 \text{ mA}$	2.7	V _{CC} – 0.5	_	-	V
		$I_{O} = -18 \text{ mA}$	3.0	V _{CC} - 0.6	_	_	V
		$I_{O} = -24 \text{ mA}$	3.0	V _{CC} – 0.8	_	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}					
		$I_{O} = 100 \mu\text{A}$	2.7 to 3.6	-	_	0.2	V
		I _O = 12 mA	2.7	_	_	0.4	V
		I _O = 24 mA	3.0	_	_	0.55	V
ILI	input leakage current	$V_I = 5.5 \text{ V or GND}$	3.6	_	±0.1	±5	μΑ
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	3.6	_	0.1	10	μА
ΔI_{CC}	additional quiescent supply current per input pin	$V_{I} = V_{CC} - 0.6 \text{ V};$ $I_{O} = 0$	2.7 to 3.6	_	5	500	μΑ

Hex inverter 74LVC04A

OVMDOL	DADAMETED	TEST COND	DITIONS		TVD (1)	MAY		
SYMBOL	PARAMETER	OTHER V _{CC} (V)		MIN.	TYP.(1)	MAX.	UNIT	
T _{amb} = -40	to +125 °C				•		1	
V _{IH}	HIGH-level input voltage		1.2	V _{CC}	_	_	V	
			2.7 to 3.6	2.0	_	_	V	
V _{IL}	LOW-level input voltage		1.2	<u> </u>	_	GND	V	
			2.7 to 3.6	_	_	0.8	V	
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_{O} = -100 \mu\text{A}$	2.7 to 3.6	$V_{CC} - 0.3$	_	_	V	
		$I_{O} = -12 \text{ mA}$	2.7	V _{CC} – 0.65	_	_	V	
		$I_{O} = -18 \text{ mA}$	3.0	V _{CC} – 0.75	_	_	V	
		$I_{O} = -24 \text{ mA}$	3.0	V _{CC} – 1	_	_	V	
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}						
		$I_{O} = 100 \mu\text{A}$	2.7 to 3.6	_	_	0.3	V	
		I _O = 12 mA	2.7	_	_	0.6	V	
		I _O = 24 mA	3.0	-	_	0.8	V	
I _{LI}	input leakage current	$V_I = 5.5 \text{ V or GND}$	3.6		_	±20	μΑ	
I _{CC}	quiescent supply current	$V_I = V_{CC}$ or GND; $I_O = 0$	3.6	_	_	40	μΑ	
ΔI_{CC}	additional quiescent supply current per input pin	$V_I = V_{CC} - 0.6 \text{ V};$ $I_O = 0$	2.7 to 3.6	_	_	5000	μΑ	

Note

^{1.} All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 $^{\circ}C.$

Hex inverter 74LVC04A

AC CHARACTERISTICS

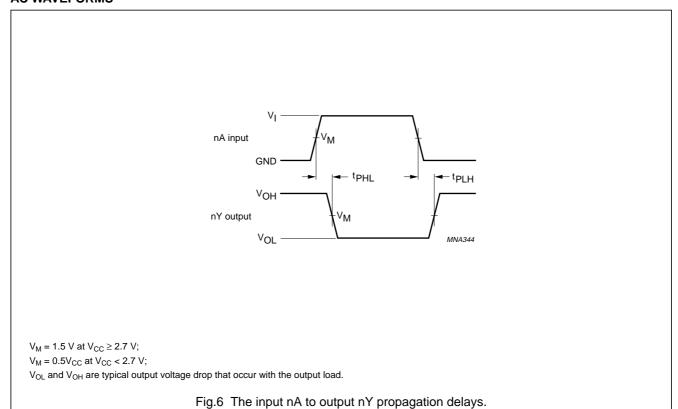
GND = 0 V; $t_r = t_f \le 2.5 \text{ ns.}$

SYMBOL	PARAMETER	TEST CONDIT	IONS	MIN.	TYP.(1)	MAX.	UNIT	
STIVIBUL	PARAMETER	WAVEFORMS	V _{CC} (V)	WIIN.	117.	WAX.	UNIT	
$T_{amb} = -40$	to +85 °C							
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 6 and 7	1.2	_	14	_	ns	
			2.7	1.5	2.2	5.5	ns	
			3.0 to 3.6	1.0	1.9	4.5	ns	
t _{sk(0)}	skew	note 2	3.0 to 3.6	_	_	1.0	ps	
T _{amb} = -40	to +125 °C		·					
t _{PHL} /t _{PLH}	propagation delay nA to nY	see Figs 6 and 7	1.2	_	_	_	ns	
			2.7	1.5	_	7.0	ns	
			3.0 to 3.6	1.0	_	6.0	ns	
t _{sk(0)}	skew	note 2	3.0 to 3.6	-	_	1.5	ps	

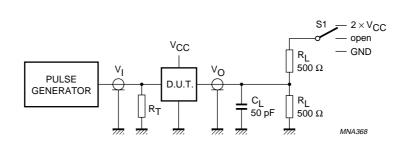
Notes

- 1. All typical values are measured at $V_{CC} = 3.3 \text{ V}$.
- 2. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

AC WAVEFORMS



Hex inverter 74LVC04A



V _{CC}	VI	t _{PLH} /t _{PHL}
1.2 V	V _{CC}	open
2.7 V	2.7 V	open
3.0 to 3.6 V	2.7 V	open

Definitions for test circuits:

R_L = Load resistor.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

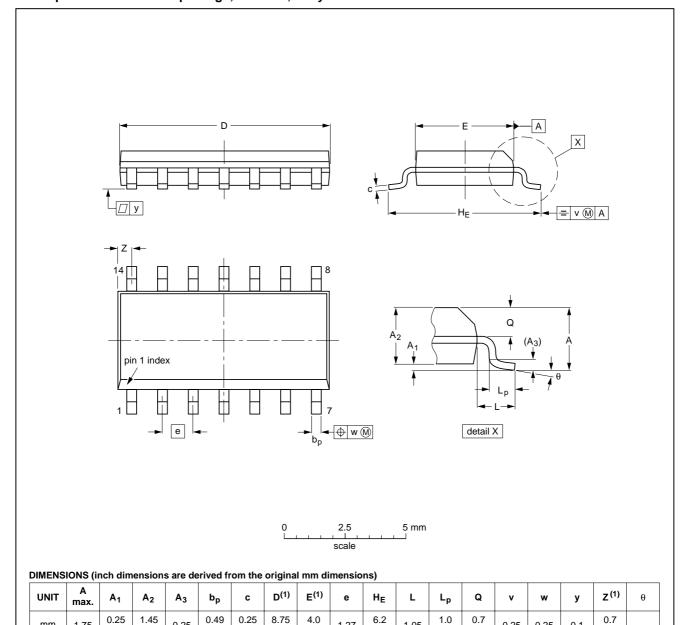
Fig.7 Load circuitry for switching times.

74LVC04A Hex inverter

PACKAGE OUTLINES

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

mm

inches

1.75

0.069

0.010

0.004

0.057

0.049

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.19

0.35

0.34

0.019 0.0100 0.014 0.0075

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012			99-12-27 03-02-19

1.27

0.05

0.244

0.228

3.8

0.16

0.15

1.05

0.041

0.039

0.016

0.028

0.024

0.25

0.01

0.25

0.01

0.1

0.004

0.3

0.028

0.012

0°

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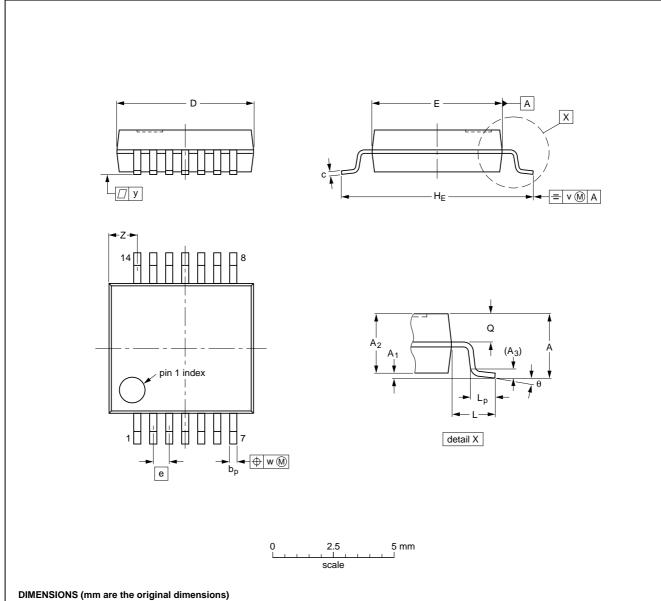
0.25

0.01

Hex inverter 74LVC04A

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UN	IIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
m	m	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

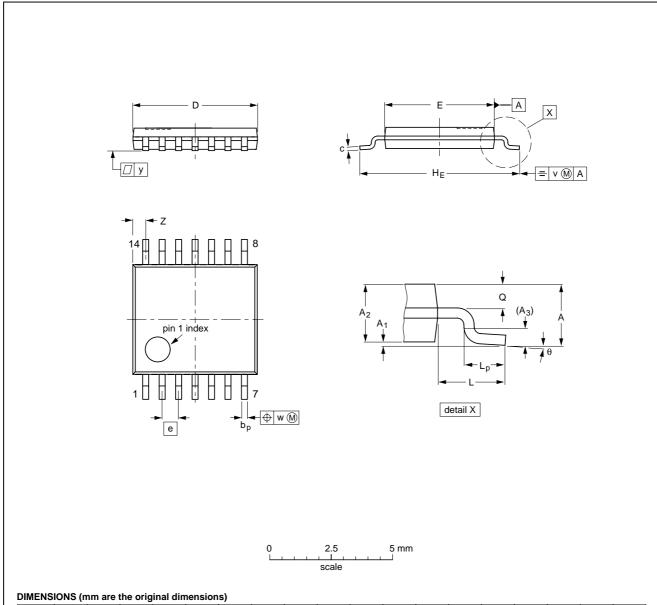
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT337-1		MO-150				99-12-27 03-02-19	

Hex inverter 74LVC04A

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E (2)	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.72 0.38	8° 0°

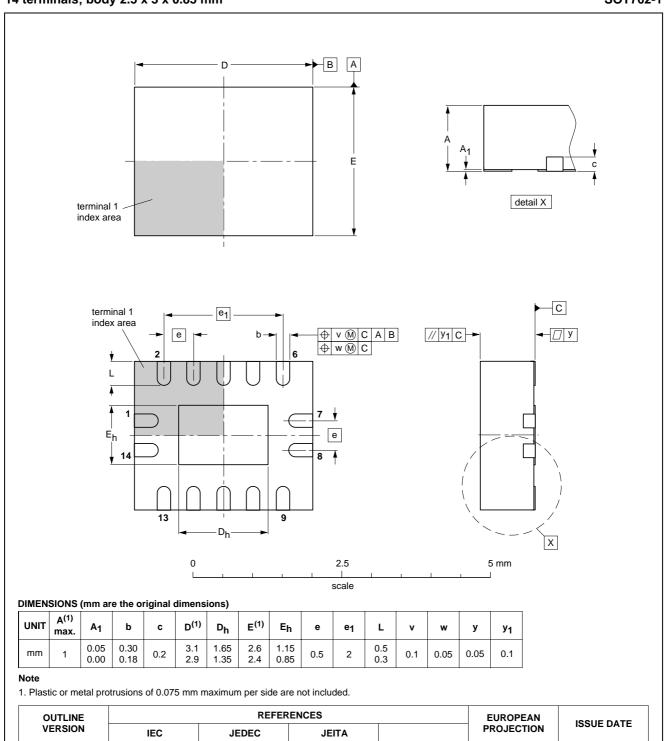
Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT402-1		MO-153				99-12-27 03-02-18	

Hex inverter 74LVC04A

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1



02-10-17

03-01-27

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2003 Feb 24 13

MO-241

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SOT762-1

Hex inverter 74LVC04A

SOLDERING

Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our "Data Handbook IC26; Integrated Circuit Packages" (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferably be kept:

- below 220 °C for all the BGA packages and packages with a thickness ≥ 2.5mm and packages with a thickness <2.5 mm and a volume ≥350 mm³ so called thick/large packages
- below 235 °C for packages with a thickness <2.5 mm and a volume <350 mm³ so called small/thin packages.

Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
 - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
 - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

 For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300 °C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320 $^{\circ}$ C.

Hex inverter 74LVC04A

Suitability of surface mount IC packages for wave and reflow soldering methods

PACKAGE ⁽¹⁾	SOLDERING METHOD				
PACKAGE	WAVE	REFLOW ⁽²⁾			
BGA, LBGA, LFBGA, SQFP, TFBGA, VFBGA	not suitable	suitable			
DHVQFN, HBCC, HBGA, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, HVQFN, HVSON, SMS	not suitable ⁽³⁾	suitable			
PLCC ⁽⁴⁾ , SO, SOJ	suitable	suitable			
LQFP, QFP, TQFP	not recommended ⁽⁴⁾⁽⁵⁾	suitable			
SSOP, TSSOP, VSO, VSSOP	not recommended ⁽⁶⁾	suitable			

Notes

- 1. For more detailed information on the BGA packages refer to the "(LF)BGA Application Note" (AN01026); order a copy from your Philips Semiconductors sales office.
- 2. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 3. These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- 4. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 5. Wave soldering is suitable for LQFP, TQFP and QFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 6. Wave soldering is suitable for SSOP, TSSOP, VSO and VSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

Hex inverter 74LVC04A

DATA SHEET STATUS

LEVEL	EVEL DATA SHEET PRODUCT STATUS(2)(3)		DEFINITION					
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.					
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.					
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).					

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Contact information

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

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Printed in The Netherlands

613508/05/pp20

Date of release: 2003 Feb 24

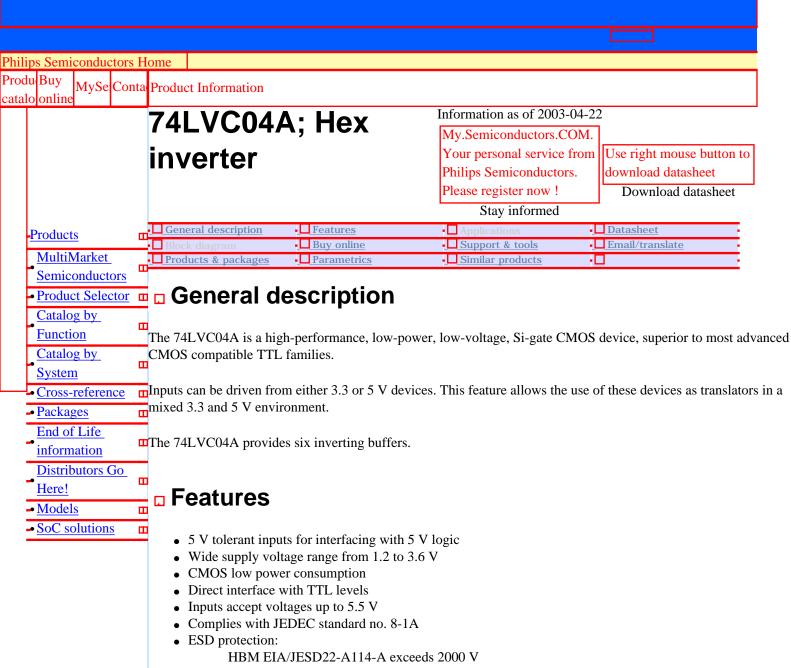
Document order number: 9397 750 10528

Let's make things better.

Philips Semiconductors







MM EIA/JESD22-A115-A exceeds 200 V.

• Specified from -40 to +85 Cel and -40 to +125 Cel.

□ Datasheet

Type number Title		Publication release date	Datasheet status	Page count	File size (kB)	Datasheet	
74LVC04A	Hex inverter	2/24/2003	Product specification	20	97	<u>Download</u>	

Parametrics

Type number	Package	Description	Propagation Delay(ns)	Voltage	of	Power Dissipation Considerations	Logic Switching Levels	Output Drive Capability
74LVC04AD	SOT108-1 (SO14)	Hex Inverter	4~6	Low	14	Low Power or Battery Applications	TTL	Medium
74LVC04ADB	SOT337-1 (SSOP14)	Hex Inverter	4~6	Low	14	Low Power or Battery Applications	TTL	Medium
74LVC04APW	SOT402-1 (TSSOP14)	Hex Inverter	4~6	Low	14	Low Power or Battery Applications	TTL	Medium

□ Products, packages, availability and ordering

Type number	North American type number	Ordering code (12NC)	Marking/Packing IC packing info	Package	Device status	Buy online
74LVC04AD	74LVC04AD	9352 424 00112	Standard Marking * Tube	SOT108-1 (SO14)	Full production	order this -
	74LVC04AD- T	9352 424 00118	Standard Marking * Reel Pack, SMD, 13"	SOT108-1 (SO14)	Full production	order this -
74LVC04ADB	74LVC04ADB	9352 424 10112	Standard Marking * Tube	SOT337-1 (SSOP14)	Full production	order this -
	74LVC04ADB- T	9352 424 10118	Standard Marking * Reel Pack, SMD, 13"	SOT337-1 (SSOP14)	Full production	order this -
74LVC04APW	74LVC04APW	9352 424 20112	Standard Marking * Tube	SOT402-1 (TSSOP14)	Full production	order this -
	74LVC04APW- T	9352 424 20118	Standard Marking * Reel Pack, SMD, 13"		Full production	order this -

□ Similar products

74LVC04A links to the similar products page containing an overview of products that are similar in function or related to the type number(s) as listed on this page. The similar products page includes products from the same catalog tree(s), relevant selection guides and products from the same functional category.

■ Support & tools

Innovative Low Voltage Logic Solutions (date 01-Aug-00)

□ Email/translate this product information

- Email this product information.
- Translate this product information page from English to:

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